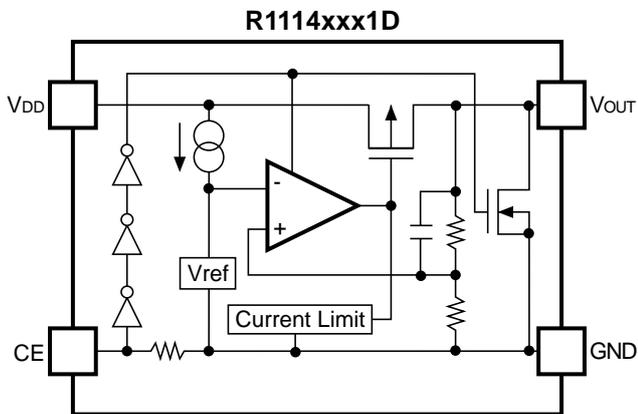
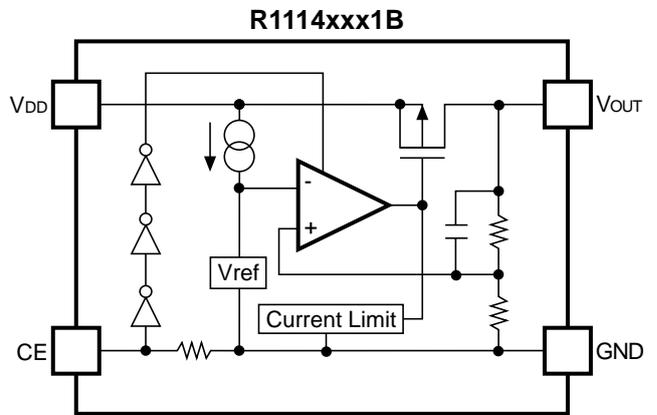
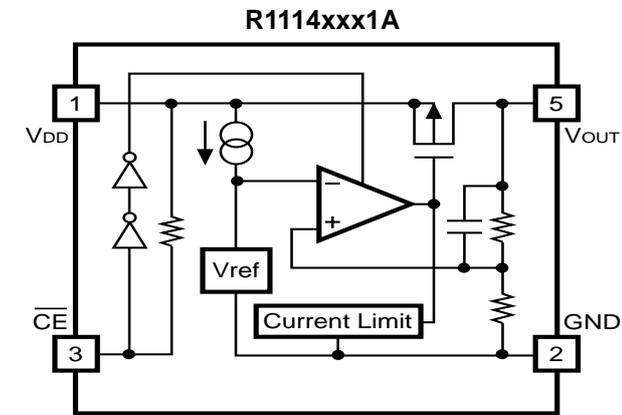


BLOCK DIAGRAMS



SELECTION GUIDE

The output voltage, auto discharge function, package, and the taping type, etc. for the ICs can be selected at the user's request.

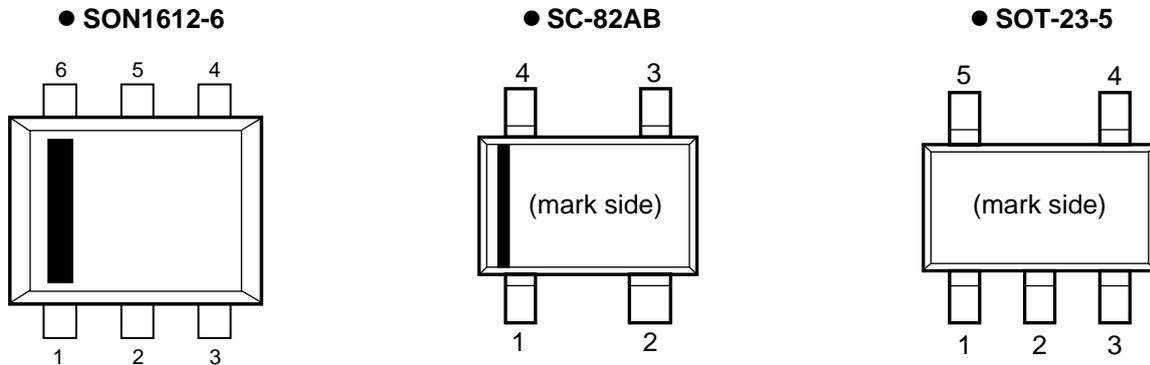
Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1114Dxx1*-TR-FE	SON1612-6	4,000 pcs	Yes	Yes
R1114Qxx1*-TR-FE	SC-82AB	3,000 pcs	Yes	Yes
R1114Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xx: The output voltage can be designated in the range from 1.5V(15) to 4.0V(40) in 0.1V steps.
(For other voltages, please refer to MARK INFORMATIONS.)

* : CE pin polarity and auto discharge function at off state are options as follows.

- (A) "L" active, without auto discharge function at off state
- (B) "H" active, without auto discharge function at off state
- (D) "H" active, with auto discharge function at off state

PIN CONFIGURATION



PIN DESCRIPTIONS

• R1114D

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	V_{OUT}	Output pin
4	NC	No Connection
5	GND	Ground Pin
6	\overline{CE} or CE	Chip Enable Pin

• R1114Q

Pin No.	Symbol	Description
1	\overline{CE} or CE	Chip Enable Pin
2	GND	Ground Pin
3	V_{OUT}	Output pin
4	V_{DD}	Input Pin

• R1114N

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	\overline{CE} or CE	Chip Enable Pin
4	NC	No Connection
5	V_{OUT}	Output pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	6.5	V
V_{CE}	Input Voltage (\overline{CE} or CE Pin)	6.5	V
V_{OUT}	Output Voltage	$-0.3 \sim V_{IN} + 0.3$	V
I_{OUT}	Output Current	200	mA
P_D	Power Dissipation (SON1612-6) *	500	mW
	Power Dissipation (SC-82AB) *	380	
	Power Dissipation (SOT-23-5) *	420	
T_{opt}	Operating Temperature Range	$-40 \sim 85$	$^{\circ}C$
T_{stg}	Storage Temperature Range	$-55 \sim 125$	$^{\circ}C$

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

• R1114xxx1A

T_{opt}=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V _{OUT}	Output Voltage	V _{IN} = Set V _{OUT} +1V 1mA ≤ I _{OUT} ≤ 30mA	×0.980		×1.020	V
I _{OUT}	Output Current	V _{IN} -V _{OUT} = 1.0V	150			mA
ΔV _{OUT} /ΔI _{OUT}	Load Regulation	V _{IN} = Set V _{OUT} +1V 1mA ≤ I _{OUT} ≤ 150mA		22	40	mV
V _{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I _{SS}	Supply Current	V _{IN} = Set V _{OUT} +1V, I _{OUT} = 0mA		75	95	μA
I _{standby}	Supply Current (Standby)	V _{IN} = Set V _{OUT} +1V V _{CE} = V _{DD}		0.1	1.0	μA
ΔV _{OUT} /ΔV _{IN}	Line Regulation	V _{OUT} > 1.7V, Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6.0V (V _{OUT} ≤ 1.7V, 2.2V ≤ V _{IN} ≤ 6.0V) I _{OUT} = 30mA		0.02	0.10	%/V
RR	Ripple Rejection	f=1kHz f=10kHz Ripple 0.5Vp-p V _{OUT} > 1.7V, V _{IN} -V _{OUT} = 1.0V V _{OUT} ≤ 1.7, V _{IN} -V _{OUT} = 1.2V I _{OUT} = 30mA		70 60		dB
V _{IN}	Input Voltage		2.0		6.0	V
ΔV _{OUT} /ΔT _{opt}	Output Voltage Temperature Coefficient	I _{OUT} = 30mA -40°C ≤ T _{opt} ≤ 85°C		±100		ppm/°C
I _{SC}	Short Current Limit	V _{OUT} = 0V		40		mA
R _{PU}	$\overline{\text{CE}}$ Pull-up Resistance		0.7	2.0	8.0	MΩ
V _{CEH}	$\overline{\text{CE}}$ Input Voltage "H"		1.5		6.0	V
V _{CEL}	$\overline{\text{CE}}$ Input Voltage "L"		0.0		0.3	V
en	Output Noise	BW = 10Hz to 100kHz		30		μVrms

• R1114xxx1B/D

T_{opt}=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V _{OUT}	Output Voltage	V _{IN} = Set V _{OUT} +1V 1mA ≤ I _{OUT} ≤ 30mA	×0.980		×1.020	V
I _{OUT}	Output Current	V _{IN} -V _{OUT} = 1.0V	150			mA
ΔV _{OUT} /ΔI _{OUT}	Load Regulation	V _{IN} = Set V _{OUT} +1V 1mA ≤ I _{OUT} ≤ 150mA		22	40	mV
V _{DIF}	Dropout Voltage	Refer to the ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE				
I _{SS}	Supply Current	V _{IN} = Set V _{OUT} +1V, I _{OUT} = 0mA		75	95	μA
I _{standby}	Supply Current (Standby)	V _{IN} = Set V _{OUT} +1V V _{CE} = GND		0.1	1.0	μA
ΔV _{OUT} /ΔV _{IN}	Line Regulation	V _{OUT} > 1.7V, Set V _{OUT} +0.5V ≤ V _{IN} ≤ 6.0V (V _{OUT} ≤ 1.7V, 2.2V ≤ V _{IN} ≤ 6.0V) I _{OUT} = 30mA		0.02	0.10	%/V
RR	Ripple Rejection	f=1kHz f=10kHz Ripple 0.5Vp-p V _{OUT} > 1.7V, V _{IN} -V _{OUT} = 1.0V V _{OUT} ≤ 1.7, V _{IN} -V _{OUT} = 1.2V I _{OUT} = 30mA		70 60		dB
V _{IN}	Input Voltage		2.0		6.0	V
ΔV _{OUT} /ΔT _{opt}	Output Voltage Temperature Coefficient	I _{OUT} = 30mA -40°C ≤ T _{opt} ≤ 85°C		±100		ppm/°C
I _{SC}	Short Current Limit	V _{OUT} = 0V		40		mA
R _{PD}	CE Pull-down Resistance		0.7	2.0	8.0	MΩ
V _{CEH}	CE Input Voltage "H"		1.5		6.0	V
V _{CEL}	CE Input Voltage "L"		0.0		0.3	V
en	Output Noise	BW = 10Hz to 100kHz		30		μVrms
R _{LOW}	On Resistance of Nch for auto-discharge (Only for D version)	V _{CE} = 0V		60		Ω

• ELECTRICAL CHARACTERISTICS by OUTPUT VOLTAGE

$T_{opt} = 25^{\circ}\text{C}$

Output Voltage V_{OUT} (V)	Dropout Voltage		
	V_{DIF} (V)		
	Condition	Typ.	Max.
$V_{OUT} = 1.5$	$I_{OUT} = 150\text{mA}$	0.38	0.70
$V_{OUT} = 1.6$		0.36	0.65
$V_{OUT} = 1.7$		0.34	0.60
$1.8 \leq V_{OUT} \leq 2.0$		0.32	0.55
$2.1 \leq V_{OUT} \leq 2.7$		0.28	0.50
$2.8 \leq V_{OUT} \leq 4.0$		0.22	0.35

TECHNICAL NOTES

When using these ICs, consider the following points:

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C_{OUT} with good frequency characteristics and ESR (Equivalent Series Resistance). (Note: If additional ceramic capacitors are connected with parallel to the output pin with an output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as same external components as ones to be used on the PCB.)

PCB Layout

Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor with a capacitance value as much as $1.0\mu\text{F}$ or more between V_{DD} and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor, as close as possible to the ICs, and make wiring as short as possible.

TEST CIRCUITS

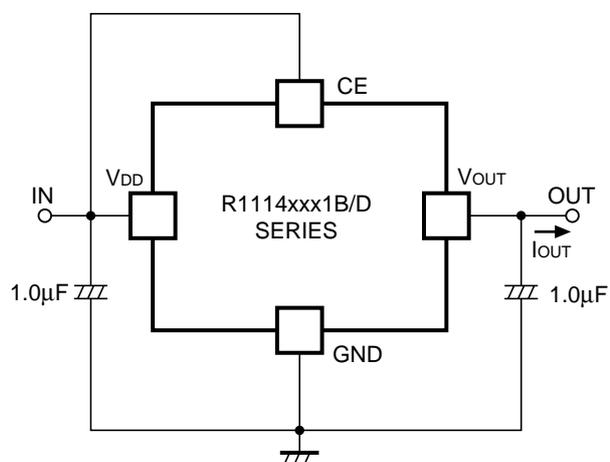


Fig.1 Standard test Circuit

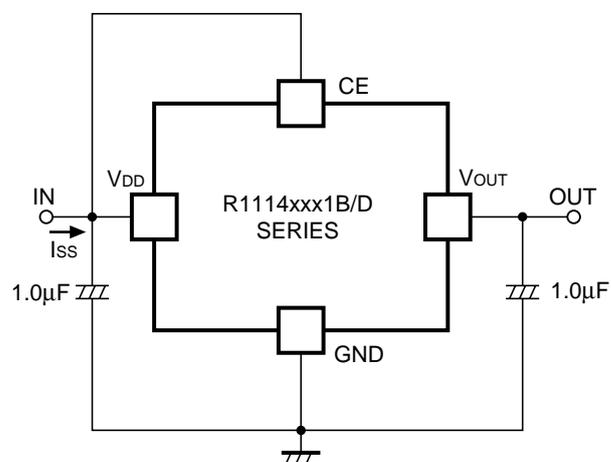


Fig.2 Supply Current Test Circuit

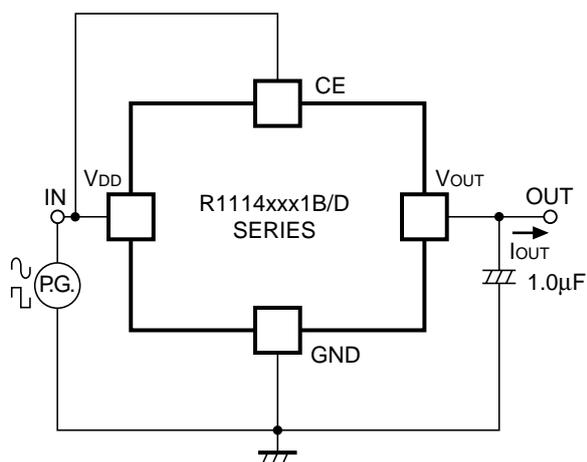


Fig.3 Ripple Rejection, Line Transient Response Test Circuit

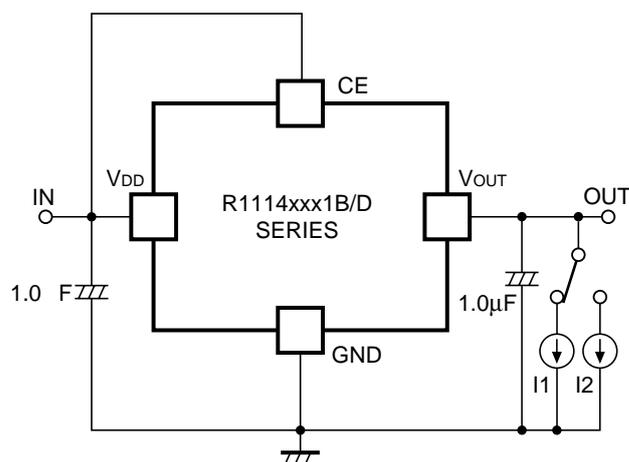
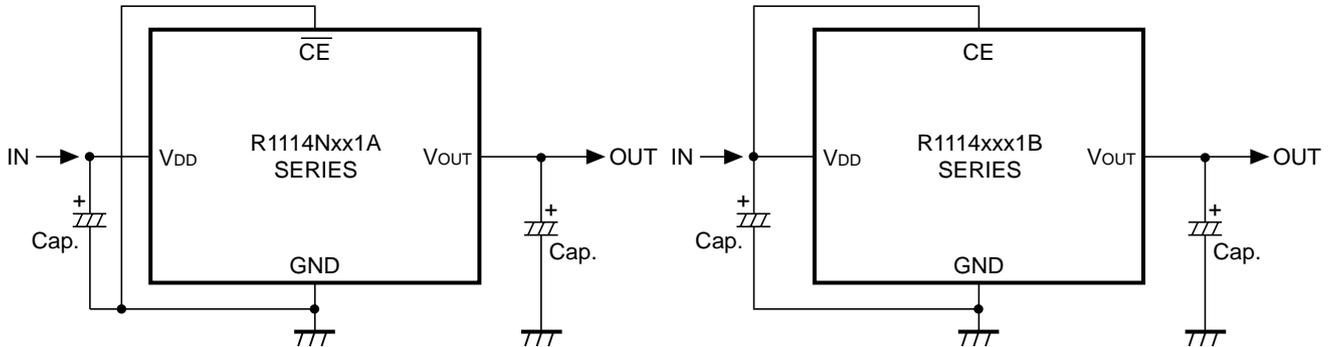


Fig.4 Load Transient Response Test Circuit

TYPICAL APPLICATIONS



(External Components)

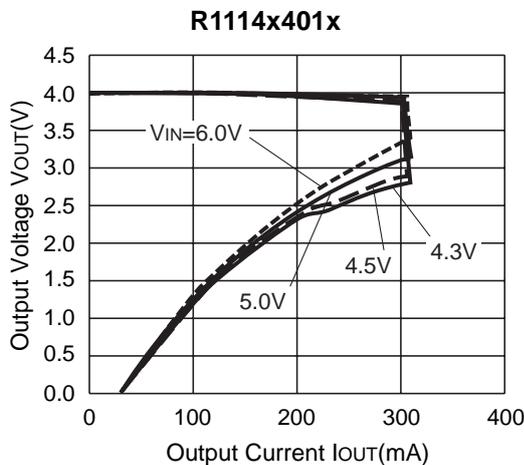
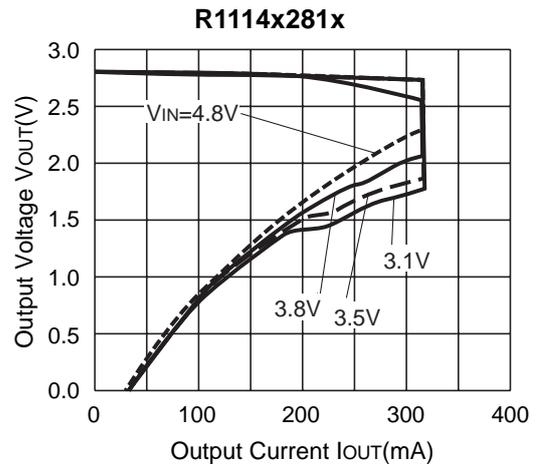
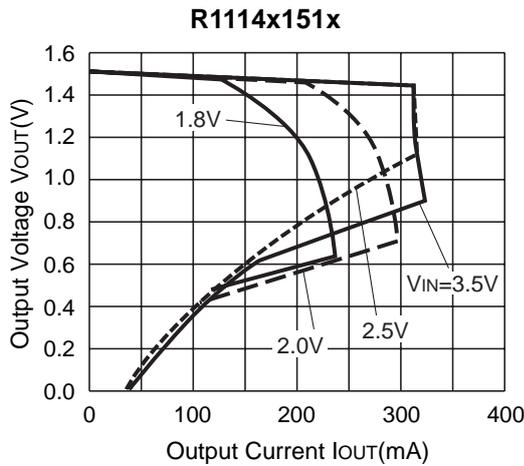
Output Capacitor; Ceramic 0.47 μ F (Set Output Voltage in the range from 2.5 to 4.0V)

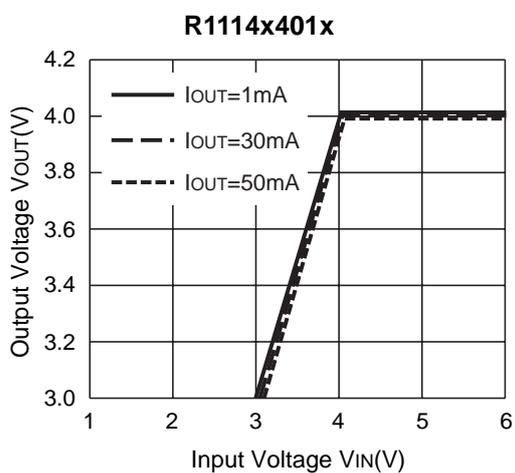
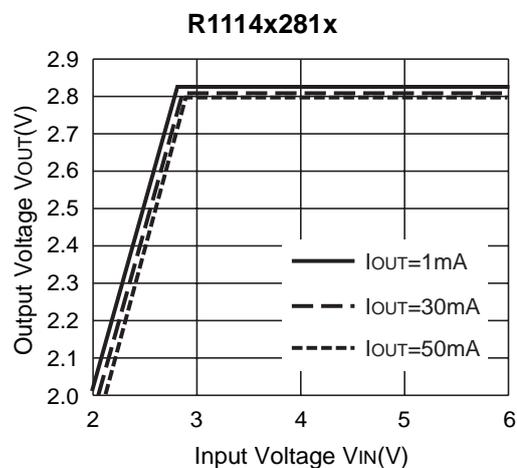
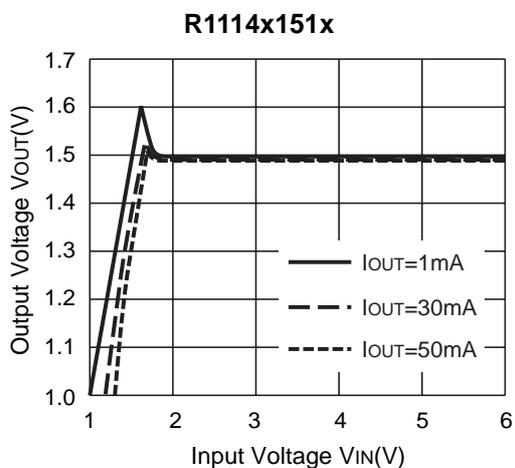
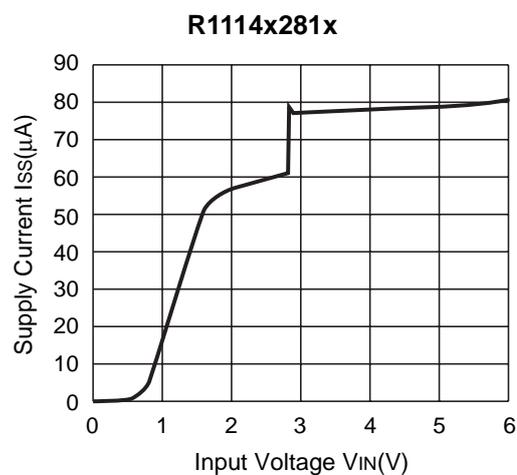
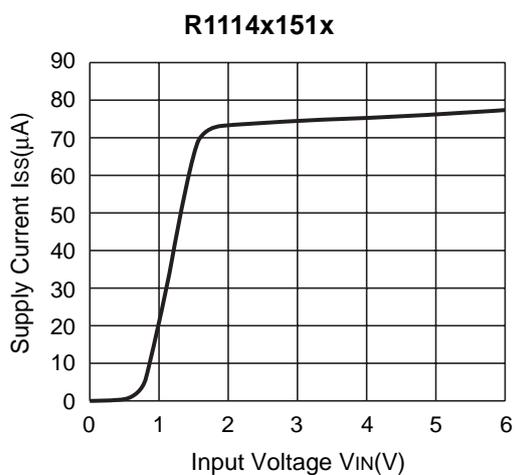
Ceramic 1.0 μ F (Set Output Voltage in the range from 1.5 to 2.4V)

Input Capacitor; Ceramic 1.0 μ F

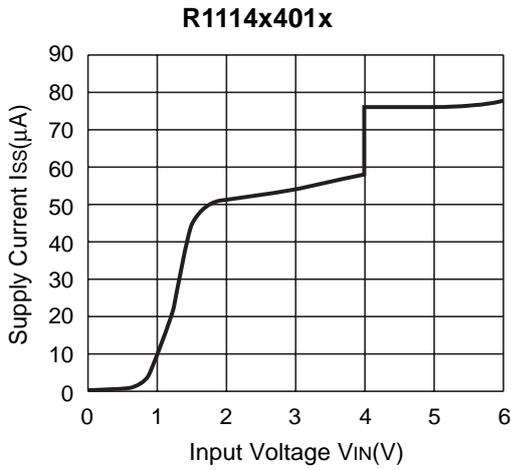
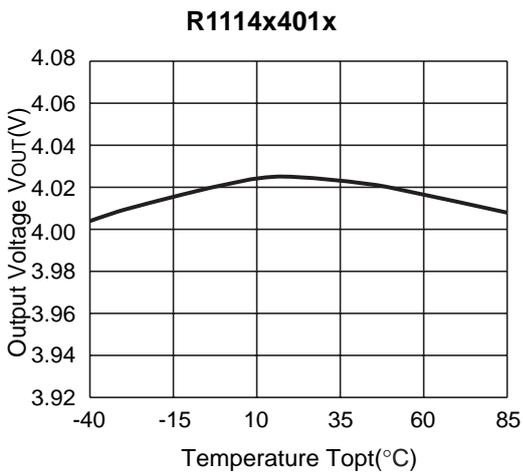
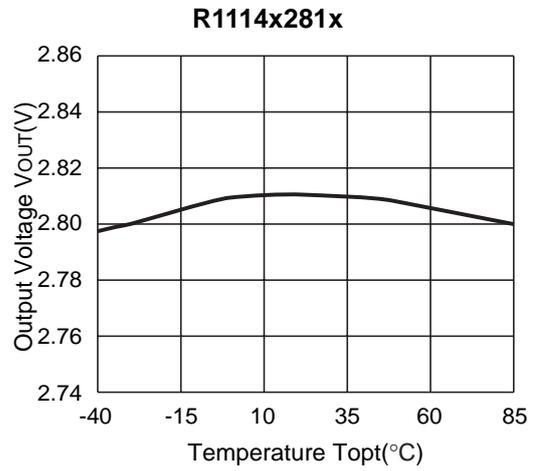
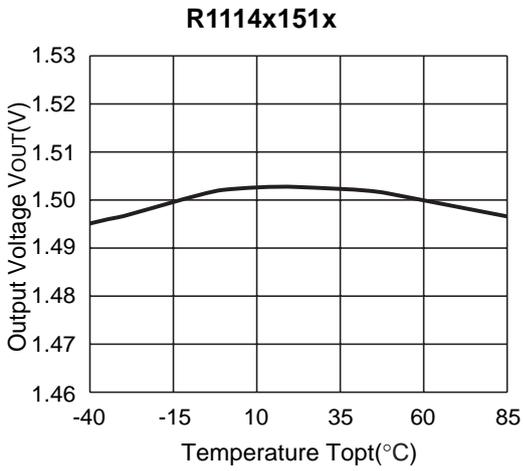
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current (Topt=25°C)

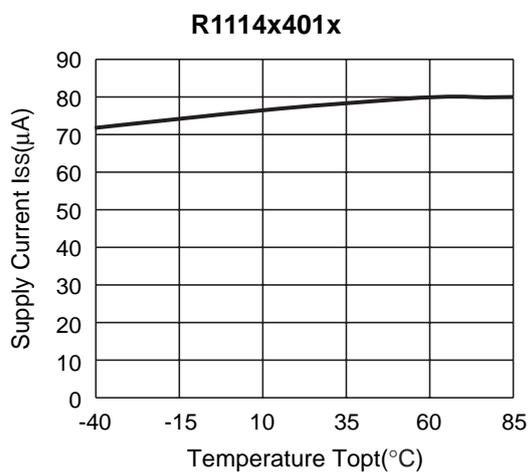
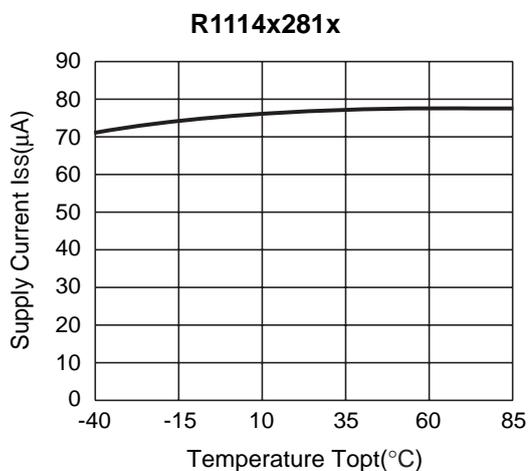
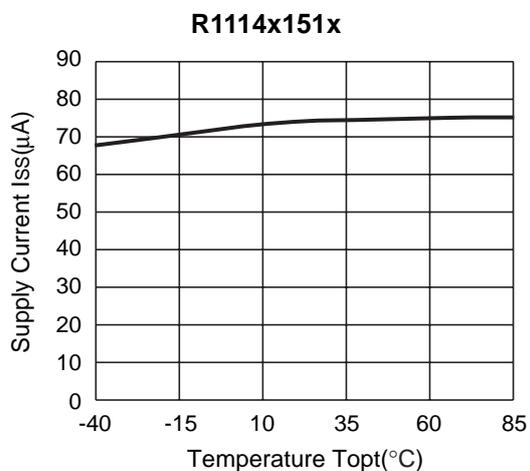


2) Output Voltage vs. Input Voltage (T_{opt}=25°C)3) Supply Current vs. Input Voltage (T_{opt}=25°C)

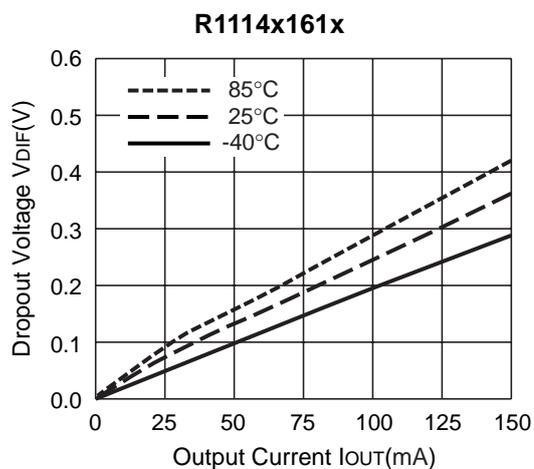
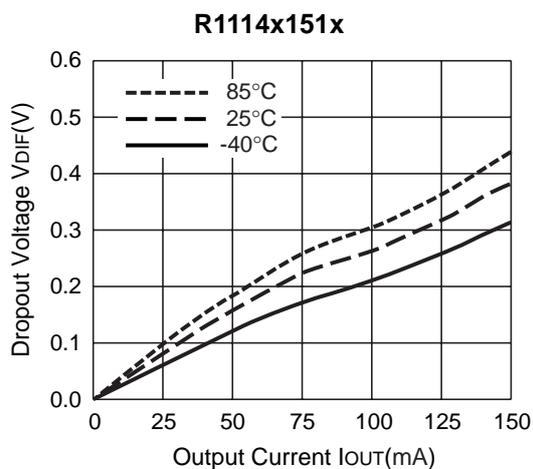
R1114x

**4) Output Voltage vs. Temperature**

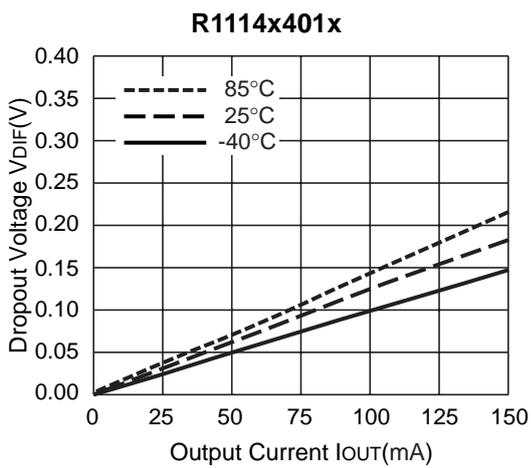
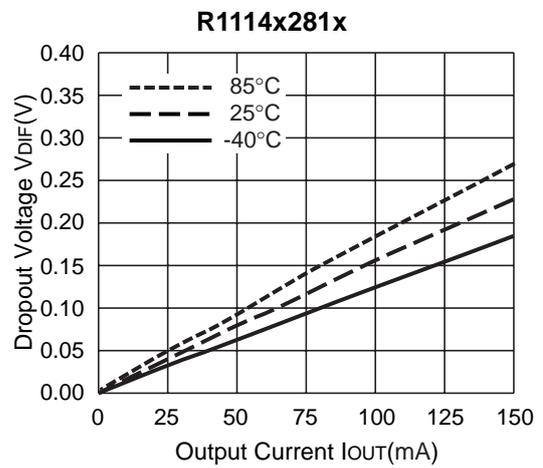
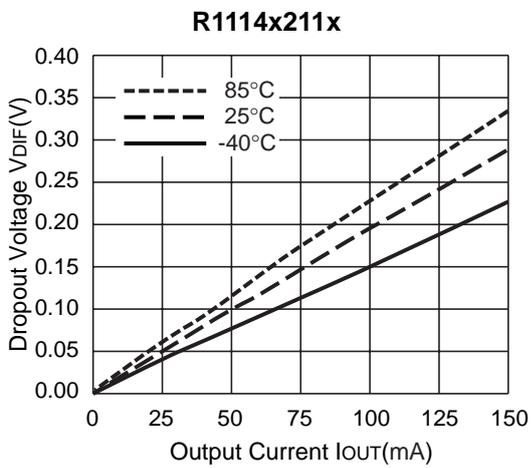
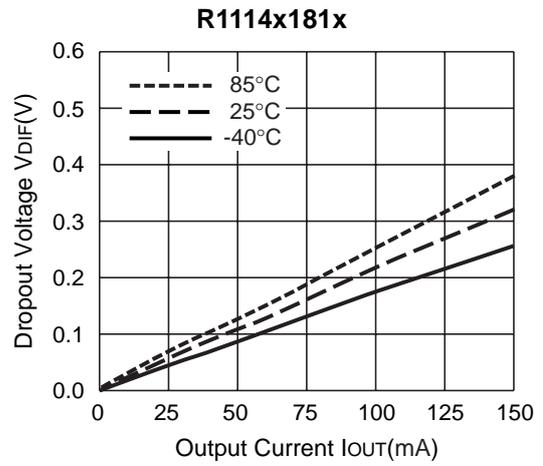
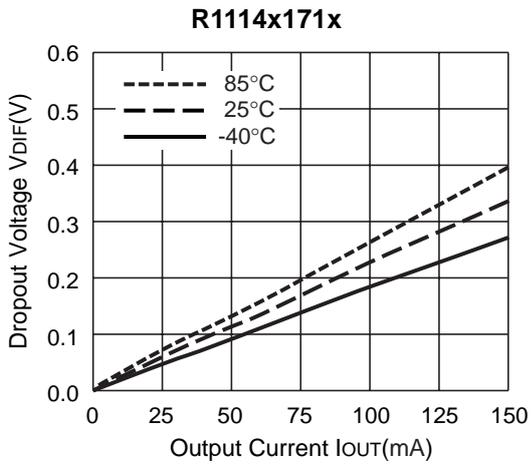
5) Supply Current vs. Temperature



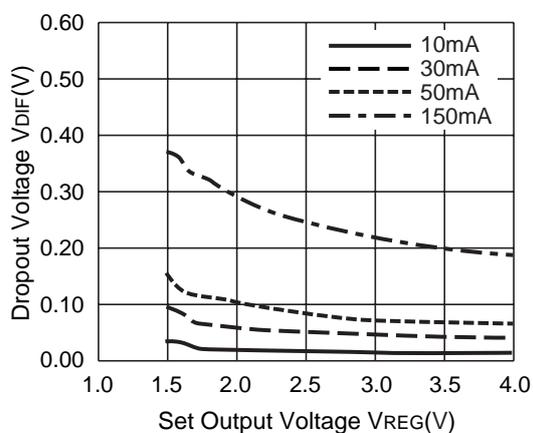
6) Dropout Voltage vs. Temperature



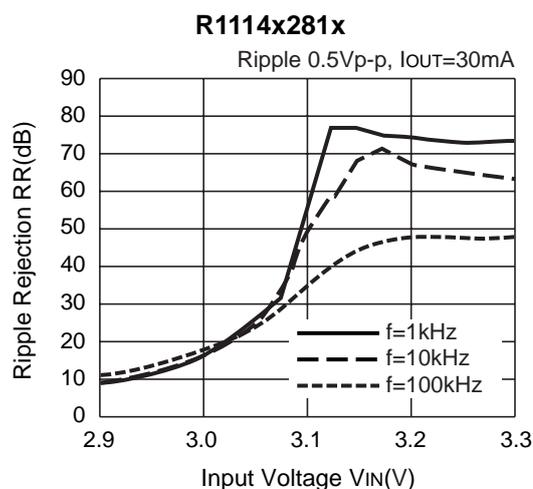
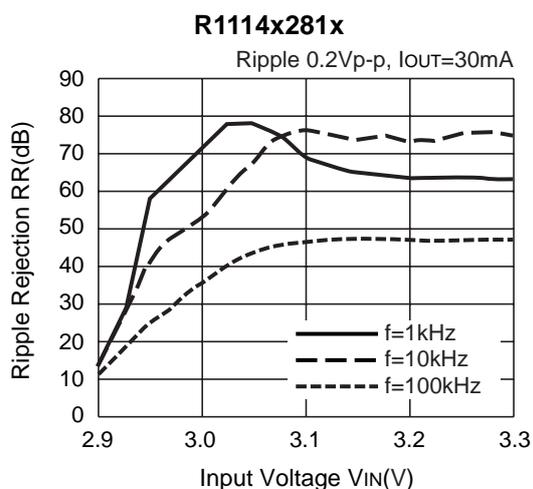
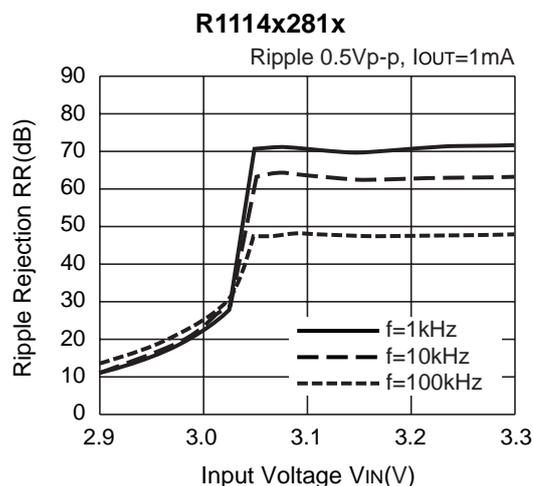
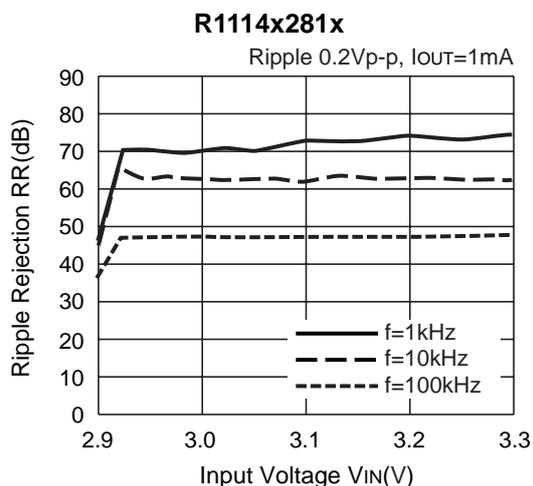
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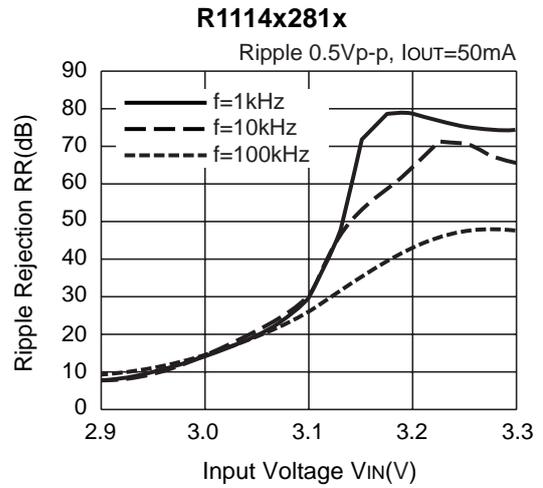
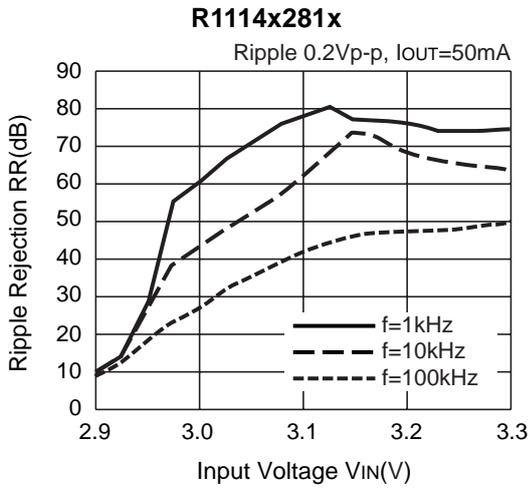


7) Dropout Voltage vs. Set Output Voltage ($T_{opt}=25^{\circ}C$)

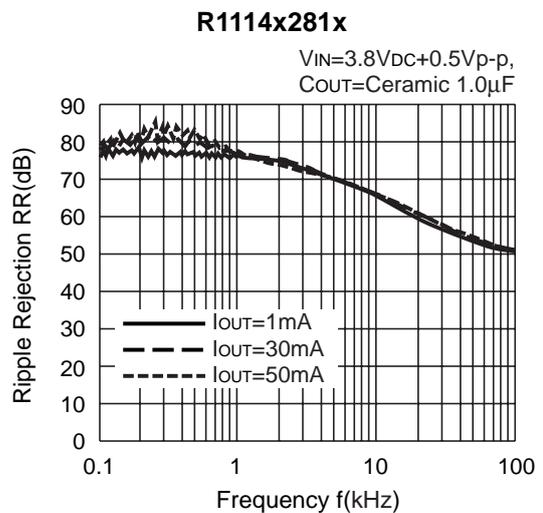
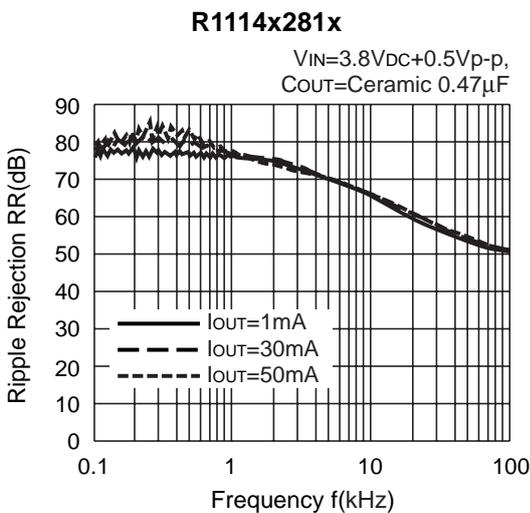
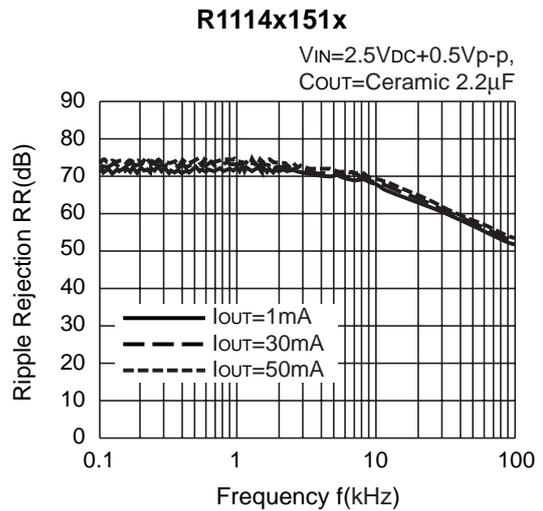
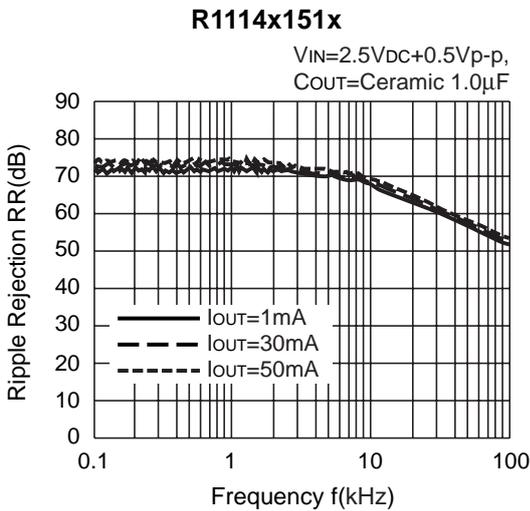


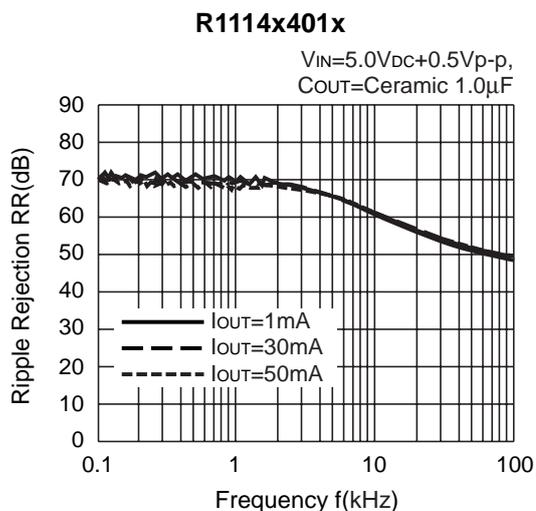
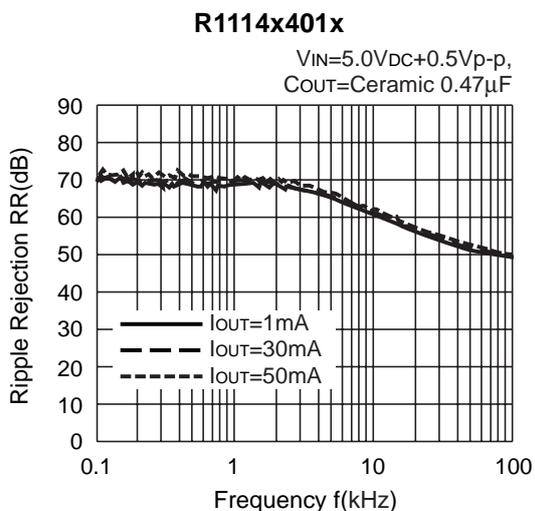
8) Ripple Rejection vs. Input Bias Voltage ($T_{opt}=25^{\circ}C$, $C_{IN}=none$, $C_{OUT}=ceramic0.47\mu F$)



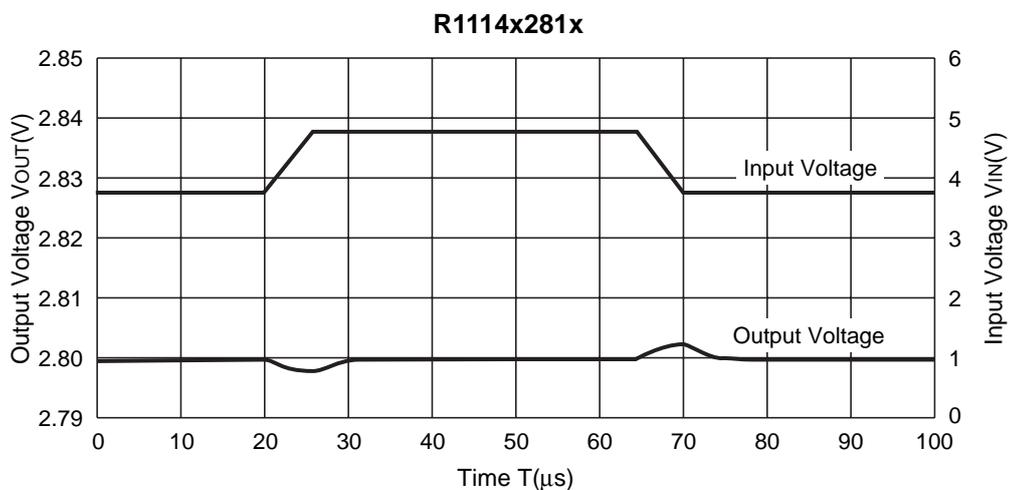
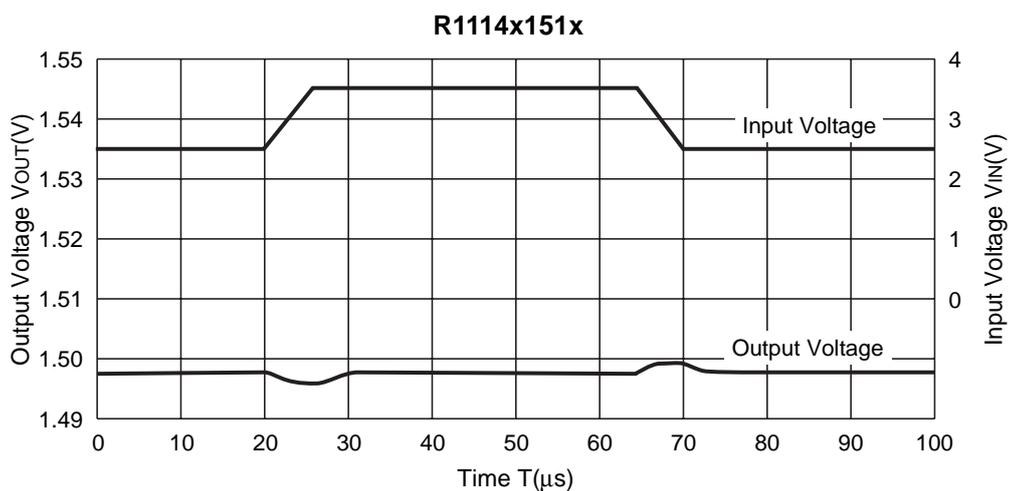


9) Ripple Rejection vs. Frequency (C_{IN}=none)



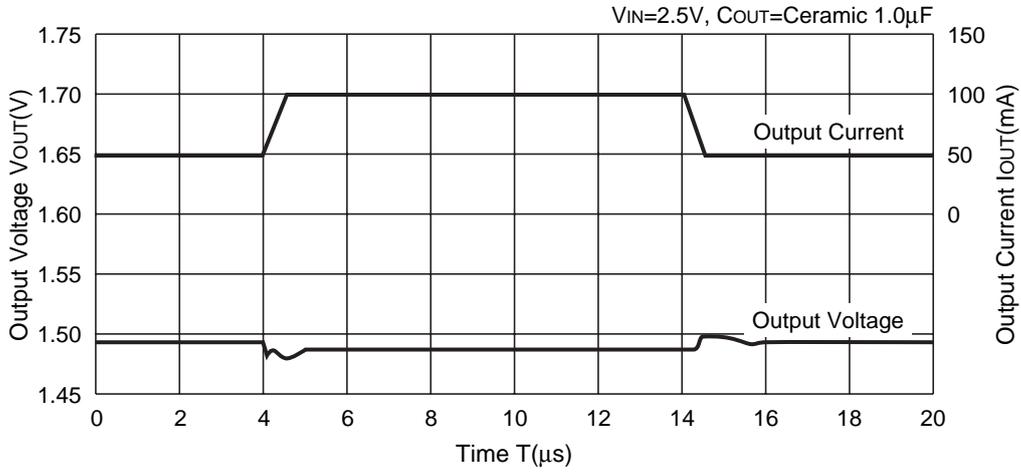


10) Input Transient Response ($I_{OUT}=30\text{mA}$, $C_{IN}=\text{none}$, $t_r=t_f=5\mu s$, $C_{OUT}=\text{Ceramic } 0.47\mu F$)

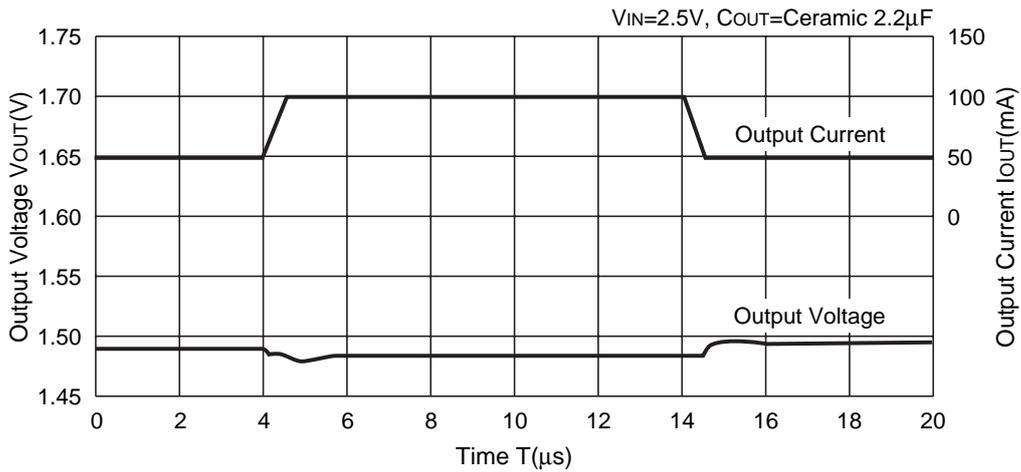


11) Load Transient Response ($t_r=t_f=0.5\mu s$, $C_{IN}=\text{Ceramic } 1.0\mu F$)

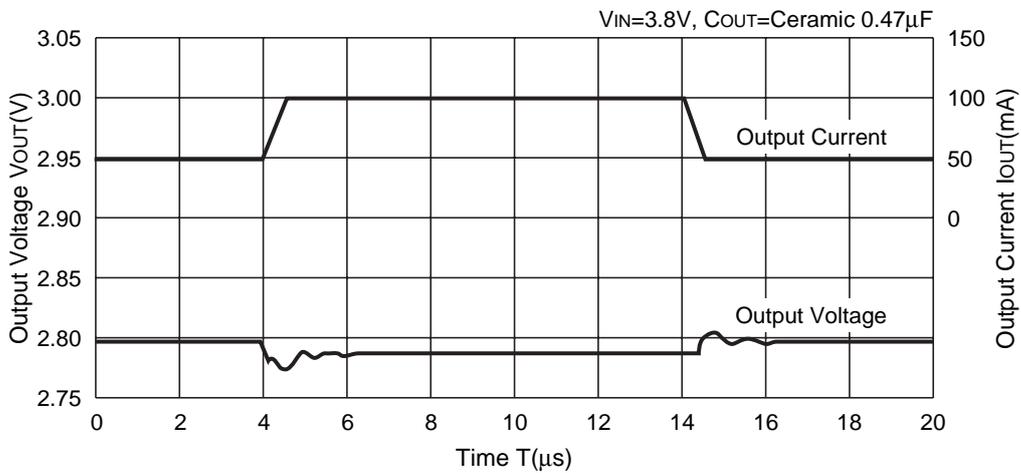
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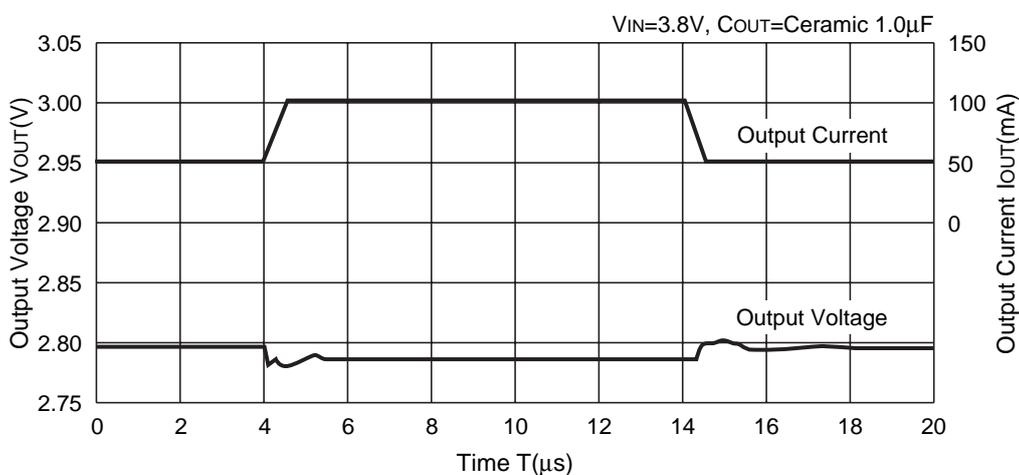
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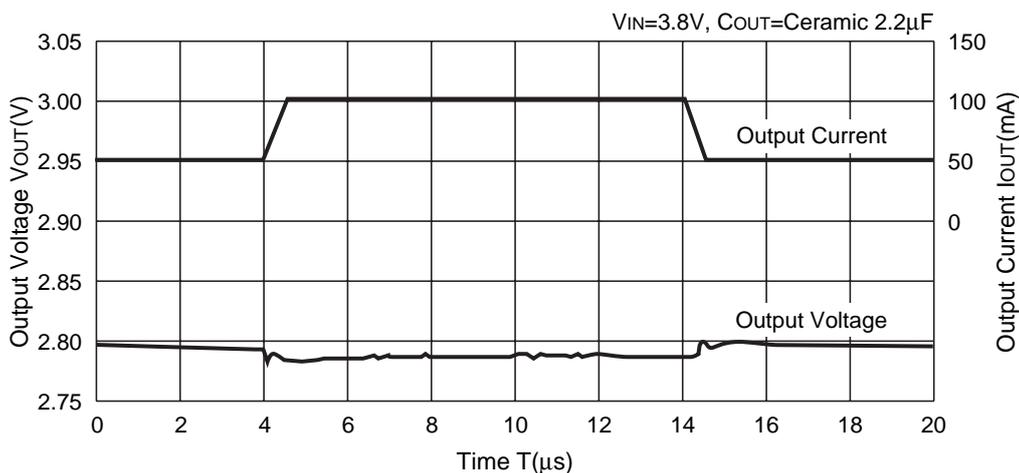
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R1114x281x

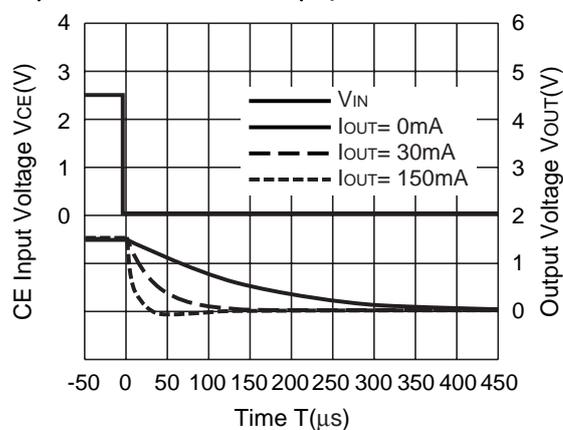
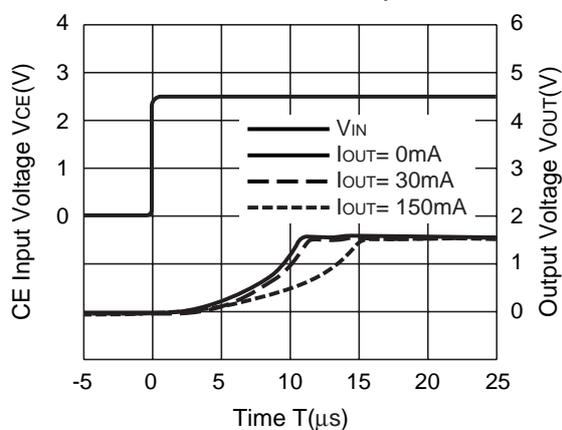


R1114x281x

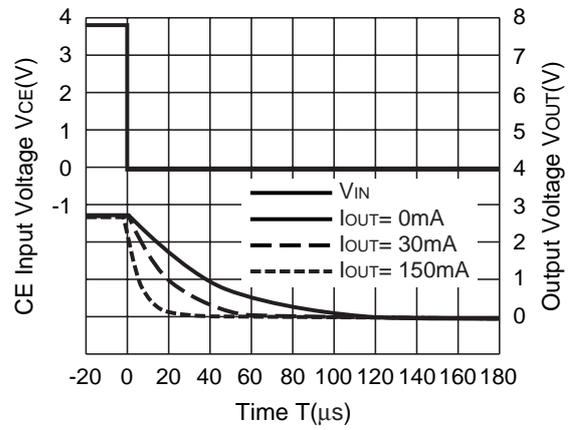
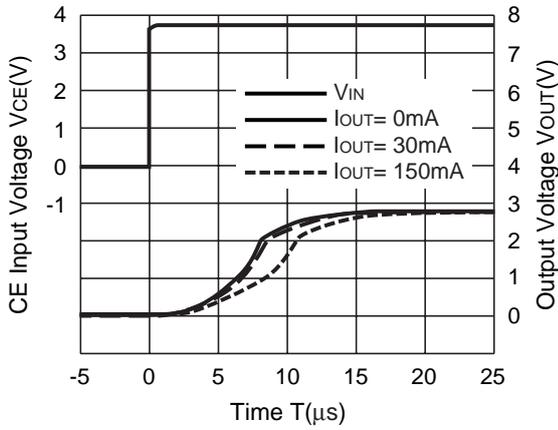


12) Turn-on/off speed with CE pin (D version)

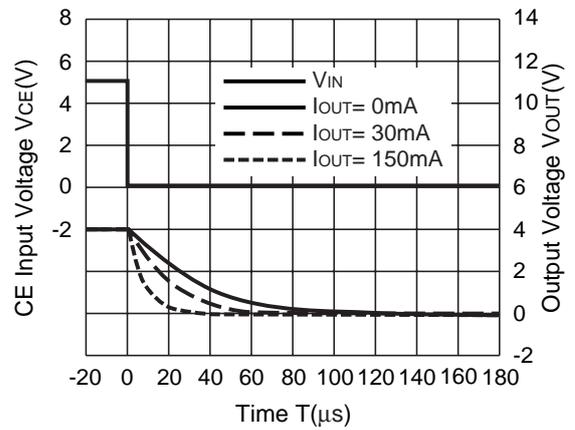
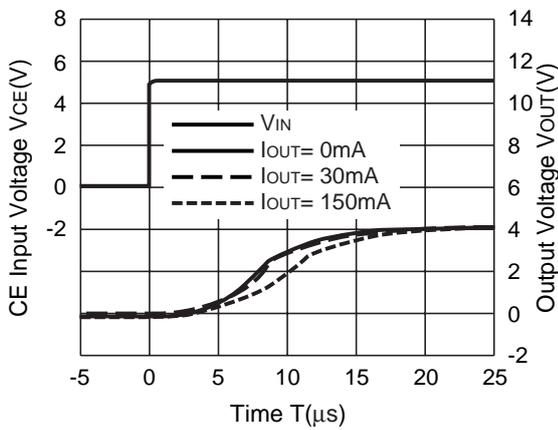
R1114x151D ($V_{IN}=2.5V$, $C_{IN}=\text{Ceramic } 1.0\mu F$, $C_{OUT}=\text{Ceramic } 1.0\mu F$)



R1114x281D ($V_{IN}=3.8V$, $C_{IN}=\text{Ceramic } 0.47\mu F$, $C_{OUT}=\text{Ceramic } 0.47\mu F$)



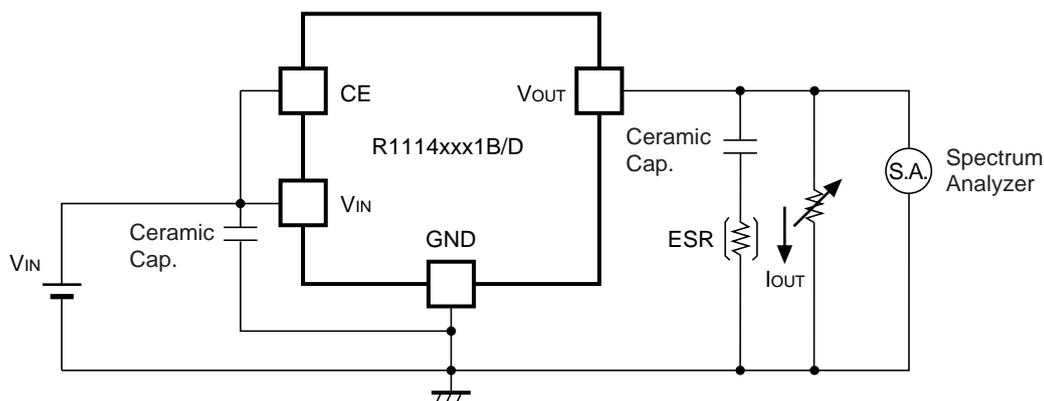
R1114x401D ($V_{IN}=5.0V$, $C_{IN}=\text{Ceramic } 0.47\mu F$, $C_{OUT}=\text{Ceramic } 0.47\mu F$)



ESR vs. Output Current

When using these ICs, consider the following points:

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C_{OUT} with good frequency characteristics and ESR (Equivalent Series Resistance) of which is in the range described as follows:



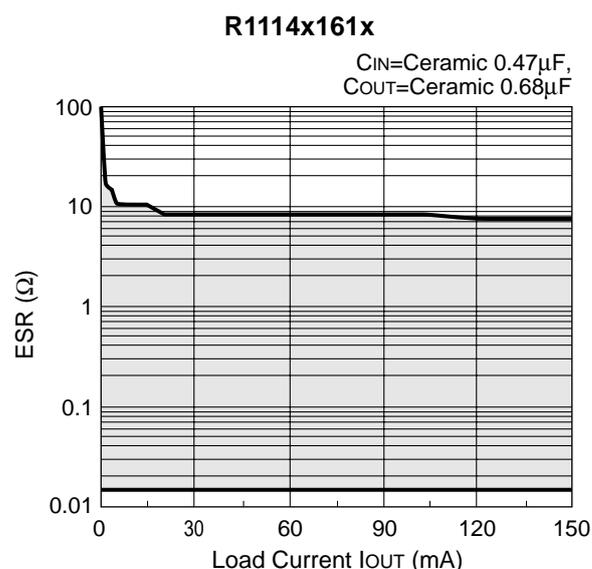
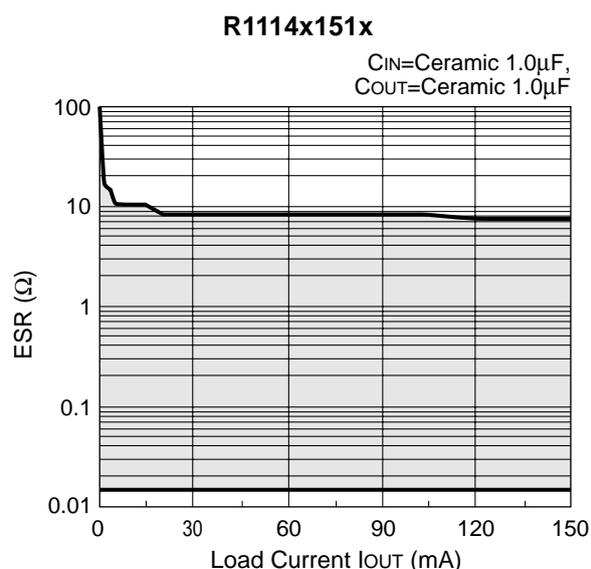
Measuring Circuit for white noise; R1114xxx1B/D

The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The conditions when the white noise level is under $40\mu\text{V}$ (Avg.) are marked as the hatched area in the graph.

(Note: If additional ceramic capacitors are connected to the Output Pin with Output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as same external components as ones to be used on the PCB.)

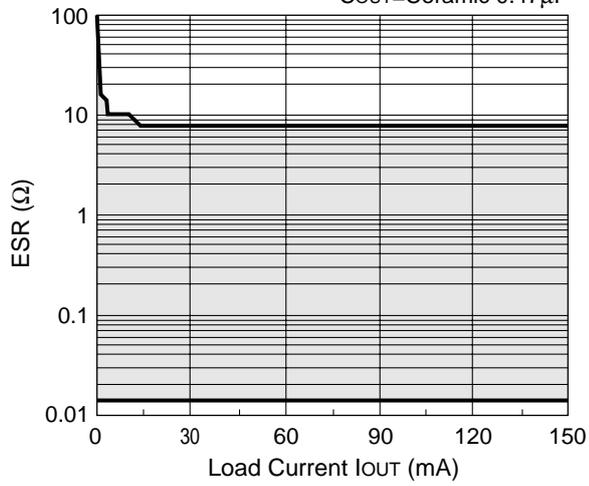
<Measurement conditions>

- (1) $V_{IN} = V_{OUT} + 1\text{V}$
- (2) Frequency Band: 10Hz to 2MHz
- (3) Temperature: -40°C to 25°C



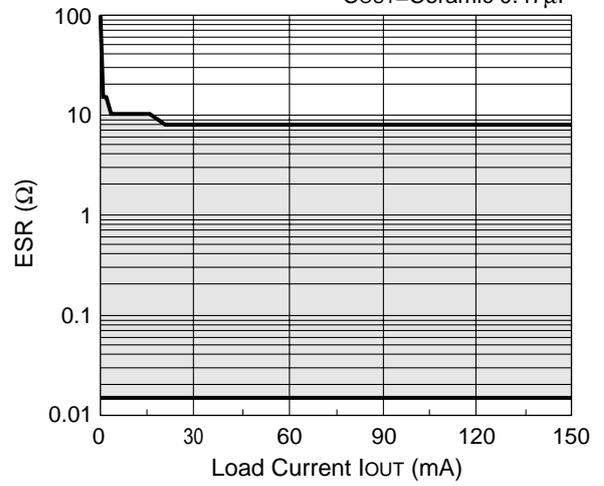
R1114x211x

C_{IN}=Ceramic 0.47μF,
C_{OUT}=Ceramic 0.47μF



R1114x281x

C_{IN}=Ceramic 0.47μF,
C_{OUT}=Ceramic 0.47μF





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